

4-Mbit (512K x 8) Static RAM

Features

- Pin and function compatible with CY7C1049CV33
- High speed

 □ t_{AA} = 10 ns
- Low active power
 □ I_{CC} = 90 mA @ 10 ns (Industrial)
- Low CMOS standby power
 □ I_{SB2} = 10 mA
- 2.0V data retention
- Automatic power down when deselected
- TTL compatible inputs and outputs
- Easy memory expansion with CE and OE features
- Available in Pb-free 36-pin (400 Mil) Molded SOJ and 44-pin TSOP II packages

Functional Description

The CY7C1049DV33 is a high performance CMOS Static RAM organized as 512K words by 8-bits. Easy memory expansion is provided by an Active LOW Chip Enable ($\overline{\text{CE}}$), an Active LOW Output Enable ($\overline{\text{OE}}$), and tri-state drivers. You can write to the device by taking Chip Enable ($\overline{\text{CE}}$) and Write Enable ($\overline{\text{WE}}$) inputs LOW. Data on the eight IO pins (IO₀ through IO₇) is then written into the location specified on the address pins (A₀ through A₁₈).

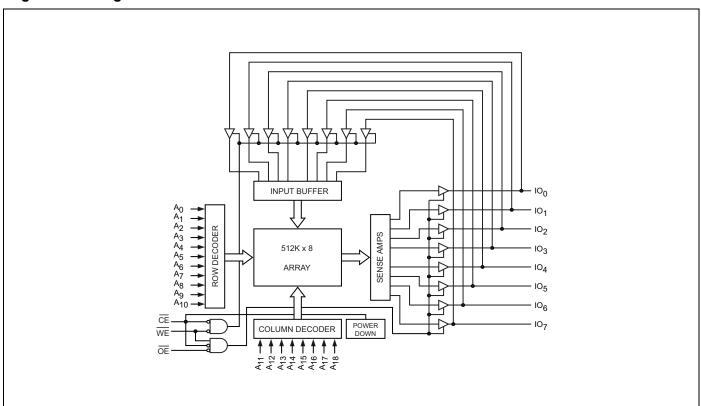
You can read from the device by taking Chip Enable (\overline{CE}) and Output Enable (\overline{OE}) LOW while forcing Write Enable (\overline{WE}) HIGH. Under these conditions, the contents of the memory location specified by the address pins appear on the IO pins.

The eight input or output pins (IO_0 through IO_7) are <u>placed</u> in a high impedance state when the device is deselected (CE HIGH), the outputs are <u>disabled</u> (OE HIGH), or during a write operation (CE LOW, and WE LOW).

The CY7C1049DV33 is available in standard 400 Mil wide 36-pin SOJ package and 44-pin TSOP II package with center power and ground (revolutionary) pinout.

Refer to the Cypress application note AN1064, SRAM System Guidelines for best practice recommendations.

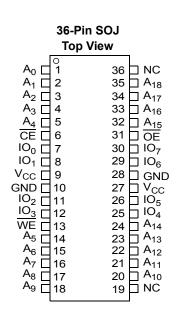
Logic Block Diagram

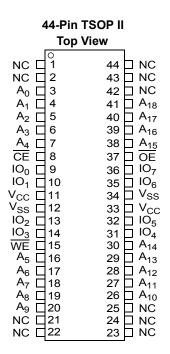


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Pin Configuration





Selection Guide

	-10 (Industrial)	-12 (Automotive) ^[1]	Unit
Maximum Access Time	10	12	ns
Maximum Operating Current	90	95	mA
Maximum CMOS Standby Current	10	15	mA

^{1.} Automotive product information is preliminary.



Maximum Ratings

Exceeding the maximum ratings may impair the useful life of the device. User guidelines are not tested.

Storage Temperature-65°C to +150°C Ambient Temperature with Power Applied55°C to +125°C Supply Voltage on V_{CC} to Relative $\mbox{GND}^{[2]}.....-0.3\mbox{V to +4.6V}$

DC Input Voltage^[2]–0.3V to V_{CC} + 0.3V

Current into Outputs (LOW)	20 mA
Static Discharge Voltage	>2001V
(MIL-STD-883, Method 3015)	
Latch up Current	>200 mA
<u> </u>	

Operating Range

Range	Ambient Temperature	V _{CC}	Speed
Industrial	-40°C to +85°C	$3.3V\pm0.3V$	10 ns
Automotive	-40°C to +125°C	$3.3V \pm 0.3V$	12 ns

Electrical Characteristics Over the Operating Range

					(Industrial)	-12 ((Automotive)	
Parameter	Description	Test Conditions	;	Min	Max	Min	Max	Unit
V _{OH}	Output HIGH Voltage	V _{CC} = Min, I _{OH} = -4.0 mA		2.4		2.4		V
V _{OL}	Output LOW Voltage	V _{CC} = Min, I _{OL} = 8.0 mA			0.4		0.4	V
V _{IH} ^[2]	Input HIGH Voltage			2.0	V _{CC} + 0.3	2.0	V _{CC} + 0.3	V
V _{IL} [2]	Input LOW Voltage ^[2]			-0.3	0.8	-0.3	0.8	V
I _{IX}	Input Leakage Current	$GND \leq V_I \leq V_CC$		-1	+1	-1	+1	μА
I _{OZ}	Output Leakage Current	GND ≤ V _{OUT} ≤ V _{CC} , Output Disabled		-1	+1	-1	+1	μА
I _{CC}	V _{CC} Operating	$V_{CC} = Max, f = f_{MAX} = 1/t_{RC}$	100 MHz		90		-	mA
	Supply Current		83 MHz		80		95	mA
			66 MHz		70		85	mA
			40 MHz		60		75	mA
I _{SB1}	Automatic CE Power down Current —TTL Inputs	$\begin{aligned} &\text{Max V}_{CC}, \overline{\text{CE}} \geq \text{V}_{\text{IH}}; \\ &\text{V}_{\text{IN}} \geq \text{V}_{\text{IH}} \text{or} \\ &\text{V}_{\text{IN}} \leq \text{V}_{\text{IL}}, \text{f} = \text{f}_{\text{MAX}} \end{aligned}$			20		25	mA
I _{SB2}	Automatic CE Power down Current —CMOS Inputs	$\begin{aligned} &\text{Max V}_{\text{CC}}, \overline{\text{CE}} \geq \text{V}_{\text{CC}} - 0.3\text{V} \\ &\text{V}_{\text{IN}} \geq \text{V}_{\text{CC}} - 0.3\text{V}, \\ &\text{or V}_{\text{IN}} \leq 0.3\text{V}, \text{f} = 0 \end{aligned}$	/,		10		15	mA

Capacitance

Tested initially and after any design or process changes that may affect these parameters.

Parameter	Description	Description Test Conditions		Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C$, $f = 1$ MHz, $V_{CC} = 3.3V$	8	pF
C _{OUT}	IO Capacitance		8	pF

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^{2.} V_{IL} (min.) = -2.0V and V_{IH} (max) = V_{CC} + 2V for pulse durations of less than 20 ns.



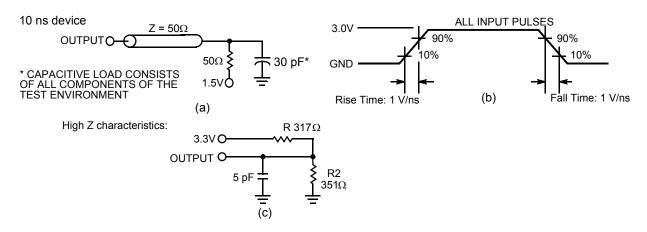
Thermal Resistance

Tested initially and after any design or process changes that may affect these parameters.

Parameter	Description	Test Conditions	SOJ Package	TSOP II Package	Unit
Θ_{JA}	Thermal Resistance (Junction to Ambient)	Still Air, soldered on a 3 × 4.5 inch, two layer printed circuit board	57.91	50.66	°C/W
Θ _{JC}	Thermal Resistance (Junction to Case)		36.73	17.17	°C/W

AC Test Loads and Waveforms

Figure 1. AC Test Loads and Waveforms [4]

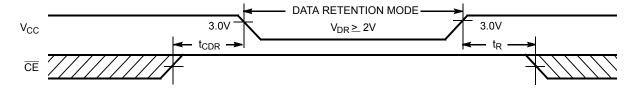


Data Retention Characteristics

Over the Operating Range

Parameter	Description	Conditions ^[5]		Min	Max	Unit
V_{DR}	V _{CC} for Data Retention			2.0		V
I _{CCDR}	Data Retention Current	$V_{CC} = V_{DR} = 2.0V, \overline{CE} \ge V_{CC} - 0.3V$	Ind'l		10	mA
		$V_{IN} \ge V_{CC} - 0.3V$ or $V_{IN} \le 0.3V$	Auto		15	mA
t _{CDR} ^[3]	Chip Deselect to Data Retention Time			0		ns
t _R ^[6]	Operation Recovery Time			t _{RC}		ns

Figure 2. Data Retention Waveform



Note

- 3. Tested initially and after any design or process changes that may affect these parameters.
- 4. AC characteristics (except High Z) are tested using the load conditions shown in Figure 1. High Z characteristics are tested for all speeds using the test load shown in Figure (c).
- 5. No input may exceed V_{CC} + 0.3V.
- 6. Full device operation requires linear V_{CC} ramp from V_{DR} to $V_{CC(min.)} \ge 50 \,\mu s$ or stable at $V_{CC(min.)} \ge 50 \,\mu s$.



AC Switching Characteristics

Over the Operating Range [7]

		-10 (Inc	dustrial)	-12 (Aut	omotive)	
Parameter	Description	Min	Max	Min	Max	Unit
Read Cycle		'	I			
t _{power} ^[8]	V _{CC} (typical) to the first access	100		100		μS
t _{RC}	Read Cycle Time	10		12		ns
t _{AA}	Address to Data Valid		10		12	ns
t _{OHA}	Data Hold from Address Change	3		3		ns
t _{ACE}	CE LOW to Data Valid		10		12	ns
t _{DOE}	OE LOW to Data Valid		5		6	ns
t _{LZOE}	OE LOW to Low Z	0		0		ns
t _{HZOE}	OE HIGH to High Z ^[9, 10]		5		6	ns
t _{LZCE}	CE LOW to Low Z ^[10]	3		3		ns
t _{HZCE}	CE HIGH to High-Z ^[9, 10]		5		6	ns
t _{PU}	CE LOW to Power up	0		0		ns
t _{PD}	CE HIGH to Power down		10		12	ns
Write Cycle	11, 12]					
t _{WC}	Write Cycle Time	10		12		ns
t _{SCE}	CE LOW to Write End	7		8		ns
t _{AW}	Address Set up to Write End	7		8		ns
t _{HA}	Address Hold from Write End	0		0		ns
t _{SA}	Address Set up to Write Start	0		0		ns
t _{PWE}	WE Pulse Width	7		8		ns
t _{SD}	Data Set up to Write End	5		6		ns
t _{HD}	Data Hold from Write End	0		0		ns
t _{LZWE}	WE HIGH to Low Z ^[10]	3		3		ns
t _{HZWE}	WE LOW to High Z ^[9, 10]		5		6	ns

Notes

Notes
 Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading of the specified I_{OL}/I_{OH} and 30 pF load capacitance.
 t_{POWER} gives the minimum amount of time that the power supply must be at stable, typical V_{CC} values until the first memory access is performed.
 t_{HZOE}: t_{HZCE}, and t_{HZWE} are specified with a load capacitance of 5 pF as in part (d) of AC Test Loads. Transition is measured when the outputs enter a high impedance state.
 At any temperature and voltage condition, t_{HZCE} is less than t_{LZCE}, t_{HZOE} is less than t_{LZOE}, and t_{HZWE} is less than t_{LZWE} for any given device.
 The internal write time of the memory is defined by the overlap of CE LOW, and WE LOW. CE and WE must be LOW to initiate a write, and the transition of either of these signals can terminate the write. The input data set up and hold timing must be referred to the leading edge of the signal that terminates the write.
 The minimum write cycle time for Write Cycle No. 2 (WE controlled, OE LOW) is the sum of t_{HZWE} and t_{SD}.



Switching Waveforms

Figure 3. Read Cycle No. 1^[13, 14]

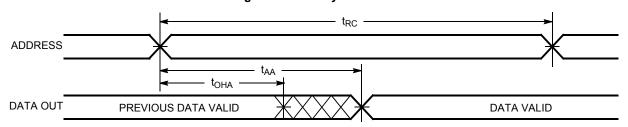


Figure 4. Read Cycle No. 2 (OE Controlled)[14, 15]

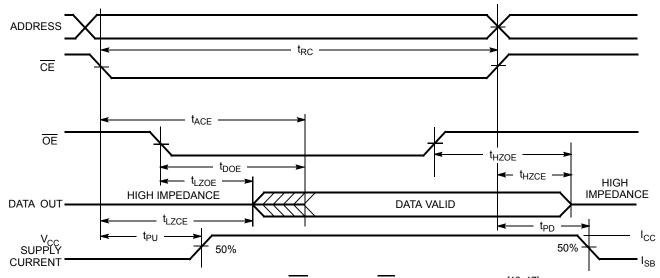
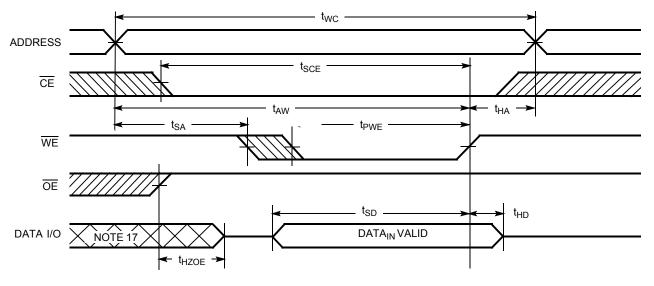


Figure 5. Write Cycle No. 1 (WE Controlled, OE HIGH During Write)[16, 17]



Notes

- 13. <u>Device</u> is continuously selected. <u>OE</u>, <u>CE</u> = V_{IL}. 14. <u>WE</u> is HIGH for read cycle.

- 14. We is first for for for coincident with CE transition LOW.
 15. Address valid prior to or coincident with CE transition LOW.
 16. Data IO is high impedance if OE = V_{IH}.
 17. If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high impedance state.



Switching Waveforms (continued)

Figure 6. Write Cycle No. 2 (WE Controlled, OE LOW)[17]

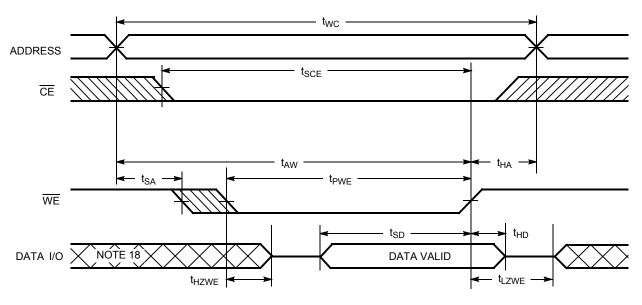
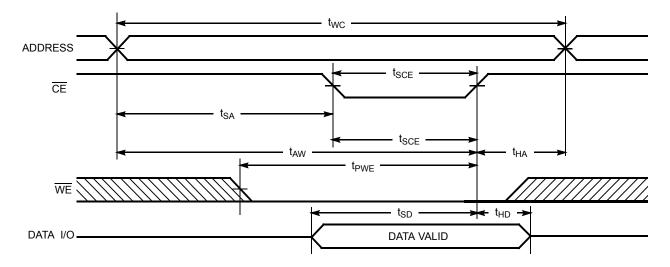


Figure 7. Write Cycle No. 3 (CE Controlled)[16, 17]



Note
18. During this period the IOs are in the output state and input signals must not be applied.



Truth Table

CE	ŌE	WE	IO ₀ –IO ₇	Mode	Power
Н	Х	X	High Z	Power down	Standby (I _{SB})
L	L	Н	Data Out	Read	Active (I _{CC})
L	Х	L	Data In	Write	Active (I _{CC})
L	Н	Н	High Z	Selected, Outputs Disabled	Active (I _{CC})

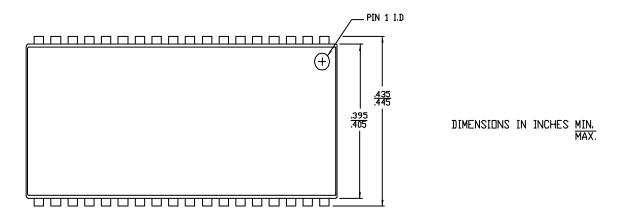
Ordering Information

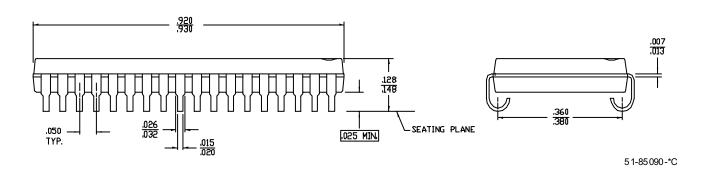
Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
10	CY7C1049DV33-10VXI	51-85090	36-pin (400-Mil) Molded SOJ (Pb-free)	Industrial
	CY7C1049DV33-10ZSXI	51-85087	44-pin TSOP II (Pb-free)	
12	CY7C1049DV33-12VXE	51-85090	36-pin (400-Mil) Molded SOJ (Pb-free)	Automotive
	CY7C1049DV33-12ZSXE	51-85087	44-pin TSOP II (Pb-free)	

Contact your local Cypress sales representative for availability of these parts.

Package Diagrams

Figure 8. 36-Pin (400-Mil) Molded SOJ (51-85090)



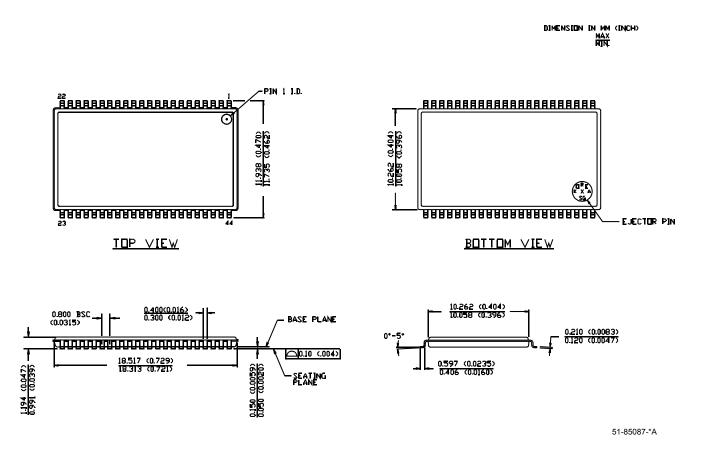


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Package Diagrams (continued)

Figure 9. 44-Pin Thin Small Outline Package Type II (51-85087)



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	ent Title: C' ent Numbe			512K x 8) Static RAM
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	201560	See ECN	SWI	Advance Datasheet for C9 IPP
*A	233729	See ECN	SYT	1.AC, DC parameters are modified as per EROS (Specification # 01-2165) 2.Pb-free offering in the Ordering Information Table
*B	351096	See ECN	PCI	Changed from Advance to Preliminary Removed 20 ns Speed bin Corrected DC voltage (min) value in maximum ratings section from - 0.5 to - 0.3V Redefined I_{CC} values for Com'l and Ind'l temperature ranges I_{CC} (Com'l): Changed from 100, 80, and 67 mA to 90, 80 and, 75 mA for 8, 10, and 12ns speed bins respectively I_{CC} (Ind'l): Changed from 80 and 67 mA to 90 and 85 mA for 10 and 12ns speed bins respectively Added $V_{IH(max)}$ specification in Note# 2 Changed reference voltage level for measurement of High Z parameters from $\pm 500~\text{mV}$ to $\pm 200~\text{mV}$ Added Data Retention Characteristics, Waveform, and footnotes 11 and 12 Changed Package Diagram name from 44-pin TSOP II Z44 to 44-pin TSOP II ZS44 Changed part names from Z to ZS in the Ordering Information Table Added 8 ns parts in the Ordering Information Table Added Pb-free Ordering Information Table
*C	446328	See ECN	NXR	Converted from Preliminary to Final Removed -8 speed bin Removed Commercial Operating Range product information Added Automotive Operating Range product information Updated Thermal Resistance table Updated footnote #8 on High Z parameter measurement Replaced Package Name column with Package Diagram in the Ordering Information table
*D	1274726	See ECN	VKN/AESA	Corrected typo in the 44-Pin TSOP II pinout

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